



## NTE2406 Silicon NPN Transistor General Purpose Amp, Surface Mount (Compl to NTE2407)

**Absolute Maximum Ratings:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Collector–Base Voltage, $V_{CBO}$	.....	75V
Collector–Emitter Voltage, $V_{CEO}$	.....	40V
Emitter–Base Voltage, $V_{EBO}$	.....	6V
Continuous Collector Current, $I_C$	.....	600mA
Total Device Dissipation (FR-5 Board, Note 1), $P_D$	.....	225mW
Derate above $+25^\circ\text{C}$	.....	1.8mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (FR-5 Board, Note 1), $R_{thJA}$	.....	556 $^\circ\text{C}/\text{W}$
Total Device Dissipation (Alumina Substrate, Note 2), $P_D$	.....	300mW
Derate above $+25^\circ\text{C}$	.....	2.4mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Alumina Substrate, Note 2), $R_{thJA}$	.....	417 $^\circ\text{C}/\text{W}$
Operating Junction Temperature Range, $T_J$	.....	$-55^\circ$ to $+150^\circ\text{C}$
Storage Temperature Range, $T_{stg}$	.....	$-55^\circ$ to $+150^\circ\text{C}$

Note 1. FR-5 = 1.000 (25.4mm) x .750 (19.05mm) x .062 (1.57mm).

Note 2. Alumina = .400 (10.2mm) x .300 (7.62mm) x .024 (.609mm), 99.5% alumina.

**Electrical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>OFF Characteristics</b>						
Collector–Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 10\mu\text{A}, I_E = 0$	75	—	—	V
Collector–Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 10\text{mA}, I_B = 0$	40	—	—	V
Emitter–Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 10\mu\text{A}, I_C = 0$	6	—	—	V
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = 60\text{V}, I_E = 0$	—	—	0.01	$\mu\text{A}$
		$V_{CB} = 60\text{V}, I_E = 0, T_A = +125^\circ\text{C}$	—	—	10	$\mu\text{A}$
	$I_{CEX}$	$V_{CE} = 60\text{V}, V_{EB(off)} = 3\text{V}$	—	—	10	nA
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = 3\text{V}, I_C = 0$	—	—	10	nA
Base Cutoff Current	$I_{BL}$	$V_{CE} = 60\text{V}, V_{EB(off)} = 3\text{V}$	—	—	20	nA

**Electrical Characteristics (Cont'd):** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>ON Characteristics (Note 3)</b>						
DC Current Gain	$h_{FE}$	$V_{CE} = 10V, I_C = 0.1mA$	35	—	—	
		$V_{CE} = 10V, I_C = 1mA$	50	—	—	
		$V_{CE} = 10V, I_C = 10mA$	75	—	—	
		$V_{CE} = 10V, I_C = 10mA, T_A = -55^\circ\text{C}$	35	—	—	
		$V_{CE} = 1V, I_C = 150mA$	50	—	—	
		$V_{CE} = 10V, I_C = 150mA$	100	—	300	
		$V_{CE} = 10V, I_C = 500mA$	40	—	—	
Collector-Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C = 150mA, I_B = 15mA$	—	—	0.3	V
		$I_C = 500mA, I_B = 50mA$	—	—	1.0	V
Base-Emitter Saturation Voltage	$V_{BE(\text{sat})}$	$I_C = 150mA, I_B = 15mA$	0.6	—	1.2	V
		$I_C = 500mA, I_B = 50mA$	—	—	2.0	V
<b>Small-Signal Characteristics</b>						
Current Gain-Bandwidth Product	$f_T$	$I_C = 20mA, V_{CB} = 20V, f = 100MHz$	300	—	—	MHz
Output Capacitance	$C_{obo}$	$V_{CB} = 10V, I_E = 0, f = 1MHz$	—	—	8	pF
Input Capacitance	$C_{ibo}$	$V_{EB} = 0.5V, I_C = 0, f = 1MHz$	—	—	25	pF
Input Impedance	$h_{ie}$	$V_{CE} = 10V, I_C = 1mA, f = 1kHz$	2	—	8	kΩ
		$V_{CE} = 10V, I_C = 10mA, f = 1kHz$	0.25	—	1.25	kΩ
Voltage Feedback Ratio	$h_{re}$	$V_{CE} = 10V, I_C = 1mA, f = 1kHz$	—	—	8	$\times 10^4$
		$V_{CE} = 10V, I_C = 10mA, f = 1kHz$	—	—	4	$\times 10^4$
Small-Signal Current Gain	$h_{fe}$	$V_{CE} = 10V, I_C = 1mA, f = 1kHz$	50	—	300	
		$V_{CE} = 10V, I_C = 10mA, f = 1kHz$	75	—	375	
Output Admittance	$h_{oe}$	$V_{CE} = 10V, I_C = 1mA, f = 1kHz$	5	—	35	μmhos
		$V_{CE} = 10V, I_C = 10mA, f = 1kHz$	25	—	200	μmhos
Collector-Base Time Constant	$r_b' C_c$	$V_{CB} = 20V, I_E = 20mA, f = 31.8MHz$	—	—	150	ps
Noise Figure	NF	$I_C = 100\mu A, V_{CE} = 10V, R_S = 1k\Omega, f = 1kHz$	—	—	4	dB
<b>Switching Characteristics</b>						
Delay Time	$t_d$	$V_{CC} = 30V, I_C = 150mA, V_{BE(\text{off})} = 0.5V, I_{B1} = 15mA$	—	—	10	ns
Rise Time	$t_r$		—	—	25	ns
Storage Time	$t_s$	$V_{CC} = 30V, I_C = 150mA, I_{B1} = I_{B2} = 15mA$	—	—	225	ns
Fall Time	$t_f$		—	—	60	ns

Note 3. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .

